82538

The Electric Properties of Single Crystals of Bismuth and Its Alloys. I. Galvanomagnetic Properties of Pure Bismuth

S/181/60/002/007/013/042 B006/B070

shows R(H) and $\frac{\Delta f}{g}$ (H) for the crystals of this type, the curves a and b showing the courses for $\theta = 90^{\circ}$ and $\theta = 0^{\circ}$. The situation for the crystals of the third type is shown in Figs. 5 and 6. For $\theta = 0^{\circ}$, the trigonal axis parallel to H. is perpendicular at $\theta = 90^{\circ}$; in the former case R(θ) and $\frac{\Delta f}{g}$ (θ) have a minimum and in the latter a maximum. Fig. 6 shows R(H) and $\frac{\Delta f}{g}$ (H) for $\theta = 90^{\circ}$ and $\theta = 0^{\circ}$. Finally, the measurement of $\frac{\Delta f}{g}$ in the longitudinal H field is briefly mentioned. Fig. 7 shows $\frac{\Delta f}{g}$ (H) for all three types of orientations. It was found that $\frac{\Delta f}{g} \simeq \alpha H^2$ holds with $\alpha_A \simeq 4.7 \cdot 10^{-10} \text{ oe}^{-2}$, $\alpha_B \simeq 21 \cdot 10^{-10} \text{ oe}^{-2}$, and $\alpha_C \simeq 29 \cdot 10^{-10} \text{ oe}^{-2}$. The following values of resistivity were found at 20° C: $f_A = 1.37 \cdot 10^{-4} \text{ ohm.cm.}$ and $f_B = f_C = 1.04 \cdot 10^{-4} \text{ ohm.cm.}$ There are 7 figures and 20 references: 8 Soviet. 5 US, 3 British, and 2 German.

Card 3/4

APPROVED FOR RELEASE: 08/10/2001 CIA-RDP86-0

CTA-RDP86-00513R000619020019-3

LUALLY, C. M.

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5/181/60/002/007/014/042 B006/B070

AUTHORS:

Gitsu, D. V., Ivanov, G. A.

TITLE:

The Electric Properties of Single Crystals of Bismuth and Its Alloys. II. The Galvanomagnetic Properties of Alloys

of Bismuth With Tellurium (Solid Solutions)

PERIODICAL:

Fizika tverdogo tela, 1960, Vol. 2, No. 7, pp. 1464-1476

TEXT: Following the previous work (I), the authors give results of measurement of the Hall coefficient R and the magnetic resistance 49/9 in magnetic fields between 1300 and 18,000 oe for single crystals of bismuth-tellurium/alloys, as well as results of measurements of $\Delta g/g$ in longitudinal magnetic field. The cylindrical single crystals investigated were again placed in three different orientations of the crystallographic axes relative to the axis of the sample: A) The trigonal axis parallel to the axis of the sample. B) One of the binary axes parallel to the axis of the sample. C) The trigonal and one of the binary axes perpendicular to the axis of the sample. (These three cases

Card 1/4

APPROVED FOR RELEASE: 08/10/2001

CIA-RDP86-00513R000619020019-3"

The Electric Properties of Single Crystals of Bismuth and Its Alloys. II. The Galvanomagnetic Properties of Alloys of Bismuth With Tellurium (Solid Solutions)

82539 S/181/60/002/007/014/042 B006/B070

are designated by A, B, B). The samples had tellurium impurities of 0.02 to 0.5 at%. Fig. 1 shows rotation diagrams of A-type crystals: R(θ) and $\frac{\Delta P}{f}$ (θ) between 0 and 60°. A clear dependence on the concentration of tellurium is seen; the higher the impurity concentration, the lower is the angular dependence. For 0.5 - 0.3 at% of tellurium, R and $\Delta P/P$ are practically independent of θ ; for 0.02 at% there is a distinct maximum at 30°. Fig. 2 shows R(H) and $\frac{\Delta P}{P}$ (H) for different Te concentrations for $\theta = 30^\circ$ and 0° (maximum and minimum in the rotation diagram). Also here, for concentrations 0.3 at% there is no more dependence on H. Analogous results were obtained on investigations of the crystals of the other two types. Fig. 3 shows R(θ) and $\frac{\Delta P}{P}$ (θ) between 0 and 180°; Fig. 4, R(H) and $\frac{\Delta P}{P}$ (H) for the type B, and Figs. 6 and 7 for the type C. The numbers in the vicinity of the curves give the concentration of tellurium; Figs. 5 and Card 2/4

The Electric Properties of Single Crystals of Bismuth and Its Alloys. II. The Galvanomagnetic Properties of Alloys of Bismuth With Tellurium (Solid Solutions) 82539 \$/181/60/002/007/014/042 B006/B070

8 show R as a function of tellurium concentration. In a longitudinal magnetic field, Δf approximately obeys the law $\Delta f \approx \alpha H^2$. Fig. 9 shows α as a function of the tellurium concentration; α falls exponentially with increasing concentration. The results of measurement of resistivity for pure bismuth and for bismuth doped with tellurium (0.02 - 0.5 at% of Te) are collected in a Table. Then, a phenomenological theory of the galvanomagnetic phenomena in crystals of the type D3d is given. The results obtained are discussed in detail. The authors finally thank Professor A. R. Regel', Doctor of Physical and Mathematical Sciences, and Professor A. V. Stepanov for their interest and advice. There are 9 figures, 1 table, and 12 references: 4 Soviet, 2 German, 2 US, 2 Japanese, and 2 British.

ASSOCIATION:

Leningradskiy gosudarstvennyy pedagogicheskiy institut

A. I. Gertsena (Leningrad State Pedagogical Institute

A. I. Gertsen)

Card 3/4

"APPROVED FOR RELEASE: 08/10/2001 CIA-RDP86-0

CIA-RDP86-00513R000619020019-3

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S/058/62/000/008/077/134 A061/A101

24.7600

AUTHORS:

Gitsu, D. V., Ivanov, G. A.

TITLE:

Anisotropy of the galvanomagnetic properties of bismuth and its

alloys with tellurium

PERIODICAL:

Referativnyy zhurnal, Fizika, no. 8, 1962, 28, abstract 8E207

("Uch.zap. Leningr. gos. ped. in-ta im. A. I. Gertsena", 1961,

207, 13 - 29)

TEXT: The anisotropy of the galvanomagnetic properties of Bi and its alloys with Te in magnetic fields of up to 18 kilogauss was investigated. The single crystals concerned had the shape of cylinders 3 - 4 mm in diameter and 5 - 8 cm long, and were oriented in one of the following three ways: A, the trigonal axis parallel to the specimen axis; B, the binary axis parallel to the specimen axis, and C, the specimen axis perpendicular to the binary and trigonal crystal axes. In type-A specimens a trigonal symmetry of the Hall coefficient $R_{\rm H}$ and the magnetoresistance $\Delta \rho/\rho$ was observed, and the maximum of the values corresponded to a magnetic field perpendicular to the binary axis. However, on

Card 1/3

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Anisotropy of the ...

Card 2/3

an increase of the Te concentration to 0.3 at.% this symmetry became circular. At the same time, the magnitude of the effects decreased. The resistance, ρ , of the alloy depended on the Te concentration, displaying a minimum at 0.2 at \$ Te? The properties of type-B specimens also became less dependent on the magnetic field orientation on Te addition, without vanishing completely. The maximum of $\Delta P/P$ sets in at an angle of, say, 20° , formed by the magnetic field and the trigonal axis. In pure bismuth $R_{\mbox{\scriptsize H}}$ has a minimum which is also shifted by 10°, and where it changes its sign to positive. This sign change is removed by a Te addition. The same effect of Te impurity is observed in C-type specimens. In pure Bi the $\Delta P/P$ curve exhibits a double maximum for a magnetic field being perpendicular to the trigonal crystal axis. ρ was found to change in the longitudinal magnetic field of all specimen types concerned. This effect was also reduced in magnitude by Te addition. These experimental results can be explained qualitatively from the consideration that the complex character of pure Bi anisotropy is due to the simultaneous presence of holes and electrons . possessing different effective masses and a different anisotropy of mobility. The Te impurity leads to a decrease of the hole concentration and to an increase

\$/058/62/000/008/076/134 A061/A101

J:1068

AUTHOR:

Ivanov, G. A.

TITLE:

Electrical properties of isoelectronic bismuth alloys

PERIODICAL: Referativnyy zhurnal, Fizika, no. 8, 1962, 26, abstract 8E194 ("Uch. zap. Leningr. gos. ped. in-ta im. A. I. Gertsena", 1961,

v. 207, 31 - 44)

ies ras autiem Proportis de de la remai es mais de la descripción de entagrafia de la la contractión de la lac

Ternary Bi-Te-Sn alloys were investigated. Isoelectronic alloys, TEXT: i.e., alloys with different impurity content, but with equal electron and hole concentrations, were found among them. This is due to the fact that the Te impurity raises the electron concentration and reduces the hole concentration, whereas the Sn impurity acts in the opposite way. For determining the concentration and the mobility of the carriers and the level of the chemical potential μ^* , a model was used besides the isotropic zone model, in which the isoenergetic surface for electrons in k-space had the shape of three ellipsoids. For simplicity the mass inside each ellipsoid was assumed to be isotropic. With this model, a better quantitative agreement between theory and experiment was

Card 1/2

CIA-RDP86-00513R000619020019-3" APPROVED FOR RELEASE: 08/10/2001

s/058/62/000/008/076/134

Electrical properties of isoelectronic bismuth alloys AO61/A101

achieved. It was found that the alloy resistance grew with the total impurity content for constant μ^* . This is explained by mobility decrease, and it is noted that the mobility of the less degenerate carriers decreases faster. The Hall coefficient measured experimentally in isoelectronic alloys with high μ^* does not depend on the composition, while in alloys with low μ^* it drops with impurity concentration. This is explained by the faster growth of the hole mobility.

I. Farbshteyn

[Abstracter's note: Complete translation]

Card 2/2

8/137/62/000/007/055/072 A057/A101 AUTHORS: Gitsu, D. V., Ivanov, G. A., Luzhkovskiy, V. G. TITLE: The microhardness of bismuth alloys and its relation to electrical characteristics of these alloys PERIODICAL: Referativnyy zhurnal, Metallurgiya, no. 7, 1962, 66, abstract 71424 ("Uch. zap. Leningr. gos. ped. in-ta im. A. I. Gertsena", 1961, 207, 45 - 50) TEXT: An investigation of the microhardness of Bi-Te and Bi-Sn-Te alloys, carried out with pressed samples, indicates apparently, that the microhardness of alloys containing a small amount of admixture is determined principally by changes of electron concentration effected by this admixture, rather than by the number of admixture atoms. T. Rumyantseva [Abstracter's note: Complete translation] Card 1/1

\$/137/63/000/001/013/019 A006/A101

AUTHORS:

Gitsu, D. Y., Ivanov, G. A.

TITLE:

On calculating the anisotropy of galvanomagnetic properties in

bismuth single crystals

PERIODICAL: Referativnyy zhurnal, Metallurgiya, no. 1, 1963, 10, abstract 1149

("Bul. Akad. Shtintse RSSMold., Izv. AN MoldSSR", 1962, no. 5,

83 - 91, Moldavian summary)

A multi-ellipsoidal Shoenberg model (D. Shoenberg "Phil. Trans. Roy. Soc.", 1952, A245) was calculated for the case of Bi and Bi with Te admixture and the results were compared with the experiment. It was found that the given model was in agreement with experimental data. It follows that in reproducing the picture of anisotropy of galvanomagnetic properties for single crystals of Bi and its alloys with Te at room temperature, it is necessary to take into account the inclination of the main axes of the ellipsoidal surfaces in the conductivity zone, to the symmetry axes of the crystal. It is easy to select a model of the zonal structure of crystals from the rotation diagrams of galvanomagnetic effects.

[Abstracter's note: Complete translation]

A. Loshmanov

Card 1/1

33338 S/181/62/004/001/004/052 24 27 00 (1043, 1137, 1482) B102/B138

AUTHORS: Gitau. D. V.

Gitsu, D. V., Ivanov, G. A., and Popov, A. M.

TITLE:

Thermoelectromotive force in bismuth and its alloys with

tellurium

PERIODICAL: Finika tverdogo tela, v. 4, no. 1, 1962, 22 - 28

TEXT: Measurement was made of the thermo-emf α of Bi single crystals with a tellurium impurity. The temperature difference was between 2 and 10°C in dependence on the Te concentration. When the temperature gradient was oriented parallel to the trigonal axis, the differential thermo-emf was denoted by α_{\parallel} , for a perpendicular gradient it was α_{\perp} ; anisotropy was thus characterized by $\alpha_{\parallel}/\alpha_{\perp}$. The measurements were carried out by a compensation method using a NNTH-1 (PPTN-1) potentiometer and copperconstantan thermocouples. α dropped rapidly with increasing Te content (from 0 - 0.4 at%); the anisotropy also decreases, vanishing at 0.1 at% Te where the α_{\parallel} and α_{\perp} curves meet. In order to explain this behavior the rotation diagrams were taken for the thermo-emf of pure and impure single Card 1/4

"APPROVED FOR RELEASE: 08/10/2001

CIA-RDP86-00513R000619020019-3

33338 \$/181/62/004/001/004/052 B102/B138

Thermoelectromotive force in...

erystals. In the first case they were elliptic and in the second circular. Exact measurements showed that there was no anisotropy between 0.1 and 0.3 at% Te. From the equations of the isoenergetic surfaces of conduction and valence bands, on the assumption that the electron and hole mean free paths were independent of carrier energy for both pure Bi and its alloys,

$$a_{j} = \frac{a_{ij} \frac{\mu}{kT} - a'_{ij} \frac{1}{eT}}{a_{ij}} . \qquad (8)$$

was found;

$$\sigma_{ij} = -\frac{2e^{2}\sqrt{2m_{1}m_{2}m_{3}}}{3\pi^{2}h^{3}m_{i}} \delta_{ij} \int_{0}^{\infty} \tau E^{3/3} \frac{\partial f_{0}}{\partial E} dE \qquad (6)$$

$$\sigma'_{ij} = -\frac{2e^{2}\sqrt{2m_{1}m_{2}m_{3}}}{3\pi^{2}h^{3}m_{i}} \delta_{ij} \int_{0}^{\infty} \tau E^{3/3} \frac{\partial f_{0}}{\partial E} dE. \qquad (7)$$

pu denotes the revel of chemical potential. For a relaxation time

Card 2/4

33338

Thermoelectromotive force in...

5/181/62/004/001/004/052 B102/B138

 $\tau_{NE}^{-1/2}$, $\alpha_{j} = \frac{k}{e} \left[\mu^{*} - \frac{2F_{1}(\mu^{*})}{F_{0}(\mu^{*})} \right]$ where μ^{*} is the reduced level of chemical

potential. The same relation is found for total thermo-emf, if the contributions of the sets of ellipsoids are added. $\alpha_{||} = \alpha_{\perp} = \frac{1}{eT} \left(\mu_{r} - \frac{A^{r}}{A} \right)$, where

$$A = -\frac{2e^2\sqrt{2m_1m_2m_2}}{3\pi^2\hbar^2} \delta_{ij} \int_{0}^{\infty} \tau E^{4_{ij}} \frac{\partial f_0}{\partial E} dE, \qquad (21)$$

$$A' = -\frac{2a^2\sqrt{2m_1m_2m_3}}{3\pi^2h^3}\delta_{ij}\int_{0}^{\infty} \tau E^{l_0}\frac{\partial f_0}{\partial E}dE.$$
 (22)

These relations hold if one electron remains in the Bi alloy with increasing Te content. This contains the vanishing anisotropy found experimentally. In anisotropic metals (Zn, Cd, Hg), semimetals (Bi, Sb) and semiconductors (CdSb) anisotropy may be considerable (Bi: $\alpha_{\parallel} = 96.6~\mu\text{m/deg}$, $\alpha_{\parallel} = 58.0~\mu\text{m/deg}$ at 18°C). There are 2 figures, 1 table, and 13 references: 6 Soviet and 7 non-Soviet. The four most recent references to English-language publications read as follows: G. E. Smith. Phys. Rev., 115, 1561, 1959; B. Abeles a. S. Meiboom. Phys. Rev., 101, 544, 1956; A. H. Wilson. The theory of metals, Cambridge, 1954;

Galvance detic properties of solid solutions of Bi-Sb in the temperature interval 77°-300°K and the influence of the important impurity tellurium on their properties. G. A. Ivanov, A. M. Popov (15 minutes).

Report presented at the 3rd National Conference on Semiconductor Compounds, Kishinev, 16-21 Sept 1963

S/181/63/005/003/037/046 B102/B180

AUTHORS:

Ivanov, G. A., and Popov, A. M.

TITLE:

Variation in the region of the weak magnetic field in bismuth and its alloys with antimony as a function of

temperature

PERIODICAL: Fizika tverdogo tela, v. 5, no. 3, 1963, 946-948

TEXT: At room temperature the weak-field region extends to 1300 oe $(H_{\rm lim})$, shrinking rapidly with falling temperature. At $77^{\rm o}$ K $H_{\rm lim} \simeq 60$ oe. For Bi single crystals, Bi-Sb single crystals (7at%Sb), and compacted specimens the field strength dependence of the resistivity ratios (applied in parallel to the triginal axis) were measured with and without field. The graph shows that $H_{\rm lim}$ for pure Bi (compacted polycrystals as well as single crystals) lies at higher field strengths (500e) than $H_{\rm lim}$ of the alloy ($\sim 600e$). As a temperature function for pure Bi $H_{\rm lim}$ increases monotonically from -200 to $0^{\rm o}$ C. There are 2 Card 1/2

S/181/63/005/003/037/046 B102/B180 Variation in the region of the weak ...

figures.

ASSOCIATION:

Leningradskiy gosudarstvennyy pedagogicheskiy institut im. A. I. Gertsena (Leningrad State Pedagogical Institute imeni A. I. Gertsen)

SUBMITTED: November 3, 1962

Card 2/2

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ACCESSION NR: AP3000622

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5/0181/63/005/005/1406/1410

AUTHOR: Gitsu, D. V.; Ivanov, G. A.

TITLE: Density of electron states in the conduction band of bismuth

SCURCE: Fizika tverdogo tela, v. 5, no. 5, 1963, 1406-1410

TOPIC TAGS: state density, Bi, Te, chemical potential, conduction band, current carrier, relaxation time

ABSTRACT: The authors have analyzed the applicability of the formula derived from the ellipsoidal model of Shoenberg (Proc. Roy. Soc. A, 170, 341, 1939) for Bi at high levels of chemical potential in the conduction band. They followed the simplest technique: comparing concentration of current carriers with the position of the chemical-potential level. They have shown that the concentration of electrons in Bi-Te Elloys at room temperature may be computed by the simple model of B. Abeles and S. Meiboom (Phys. Rev. 101, 544, 1956), with an accuracy that is limited only by the experiment, not by theory. The dominant mechanism of scattering in these alloys is of the same type occurring in atomic semiconductors. The possible density of electron states in the conduction band of Bi is directly proportional to the square root of the energy; i.e., the effective masses do not Card 1/2

change appreciably within the limits of measurements up to 0.4 ev. "In conclusion the authors express their thanks to Professor A. R. Regal' for his interest in the present work." Orig. art. has: 1 figure and 10 formulas.

ASSOCIATION: Leningradskiy goaldrastvenny'vy pedagogicheskiy institut in A. I. Gertsena (Leningrad State Pedagogical Institute)

SUBMITTED: 310ct62 DATE ACQ: 11Jun63 ENCL: 00

SUB CODE: 00 NO REF SOV: 008 OTHER: 007

L 13028-63 EWP(q)/ETT(m)/BDS AFFTC/ASD JD

ACCESSION NR: AP3000626

8/0181/63/005/005/1428/1429

AUTHOR: Ivanov, G. A.; Popov, A. M.

TITIE: Free path length of current cerriers in bismuth and in its alloys with antimony

SOURCE: Fizika tverdogo tela, v. 5, no. 5, 1963, 1428-1429

TOPIC TAGS: specific resistance, Hall constant, free path, Bi, Gu, impurity layer, current carrier, polycrystalline material

ABSTRACT: The authors have investigated changes (in the temperature interval 77-300K) in specific resistance and in the Hall constant for polycrystalline samples of Bi and for its alloys with 5b in relation to grain size and in comparison with single-crystal samples. They found the free path to be dependent on grain size, and they have concluded that the changes are due to limitation of free path of current carriers by grain boundaries in polycrystalline material. They state that considerable error may drise in evaluating concentration and mobility of current carriers in Bi-5b plicys on the basis of measurements made in polycrystalline material. Conclusions concerning the solubility of several impurities in Bi, based on the "semiconductor" path of specific resistance in

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ACCESSION NR: AP3000626

alloys, may be erroneous because of the formation of impurity layers during growth of single crystals. An alloy of Bi and 0.75 atomic percent Ge has a "semiconductor" course of specific resistance, but the authors have established that the Hall constant of this alloy is no different from the Hall constant for pure Bi in the temperature interval 77-300K. Orig. art. has: 3 figures and 1 formula.

ASSOCIATION: Leningradskiy gosudarstvenny pedagogicheskiy institut im. A. I. Gertsena (Leningrad State Pedagogical Institute)

SUBMITTED: 12Jan63

DATE ACQ: 11Jun63

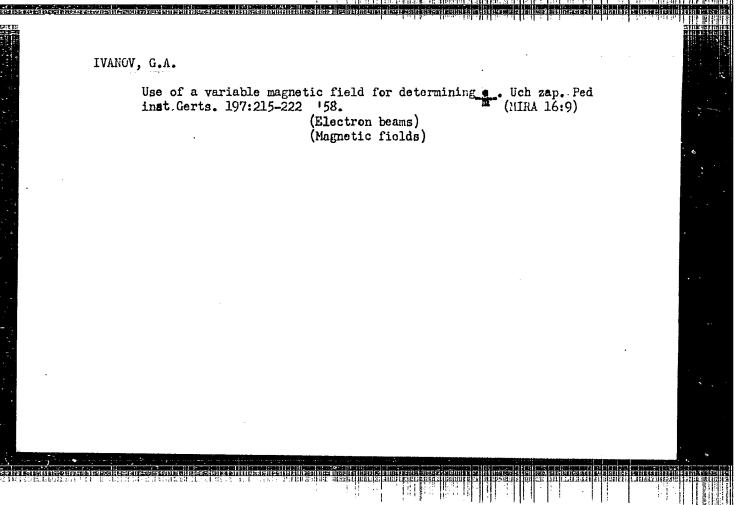
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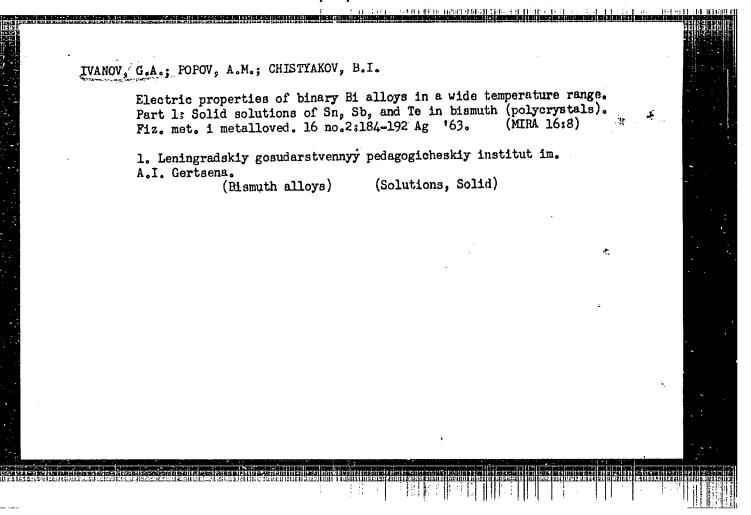
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NO REF SOV: 003

OTHER: 003

Card 2/2





ACCESSION NR: AP4009377

S/0126/63/016/006/0848/0855

AUTHORS: Ivanov, G. A.; Chistyakov, B. I.

TITLE: Electrical properties of ternary alloy of bismuth in the temperature range 77-450K. 2

SOURCE: Fizika metallov i metallovedeniye, v. 16, no. 6, 1963, 848-855

TOPIC TACS: ternary alloy, Hall effect, specific resistance, thermoelectric electromotive force, tellurium, tin, recovery alloy, electron, hole, current carrier, semiconductor, valency, atomic number

ABSTRACT: The authors present an analysis of the experimental work performed earlier (L. I. Mokiyevskiy and G. A. Ivanov, ZhTF, 1957, 27, 8, 1695; G. A. Ivanov and A. R. Regel', ZhTF, 1955, 25, 1, 49). In these experiments the properties of specific resistance, Hall effect, magnetic strength, and thermoelectric emf in the temperature range of 77-450K for a ternary alloy of bismuth with admixtures of Sn and Te were investigated. Special attention was given to the proporties of recovery alloys with an equal number of electrons and holes. The alloys had relative atomic percentages of Te impurity (ratio of Te percent to total impurity percent) of 5, 10, 15, 20, 30, 40, 50, and 75. Total impurities contents were 0.05, 0.1, 0.2 and 0.3%.

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ACCESSION NR: AP4009377

The Hall coefficient and the specific resistance were found to reach sharp extremes at characteristic temperatures. It was concluded that the concentration of the current carriers created by the components of a ternary alloy depended not only on the valencies but also on the atomic numbers of the elements of the 4th and the 6th groups. Orig. art. has: 6 figures and 1 table.

ASSOCIATION: Leningradskiy pedagogicheskiy institut im. A. I. Gertsens (Leningrad Teachers Institute)

SUBMITTED: 12Dec62

DATE ACQ: 03Feb64

ENCL: 00

SUB CODE: IC, SS

NO REF SOV: 010

OTHER: 009

Card 2/2

ACCESSION NR: APLO19863

8/0181/64/006/003/0938/0940

AUTHOR: Ivanov, G. A.

TITLE: Computing the concentration and mobility of current carriers in bismuth

SOUPCE: Fizika tverdogo tela, v. 6, no. 3, 1964, 938-940

TOPIC TACS: semiconductor carrier, semiconductor, semiconductor property

ABSTRACT: The indicated properties have been determined by several workers at various temperatures. The author examines these results and compares them with computed values. The results are summarized in Fig. 1 on the Enclosure. It may be seen that the carrier concentration varies approximately at T3/2 through a wide range of temperature (120-350K), and electron mobility varies as T-5/2 through the same range. Orig. art. has: 1 figure and 11 formulas.

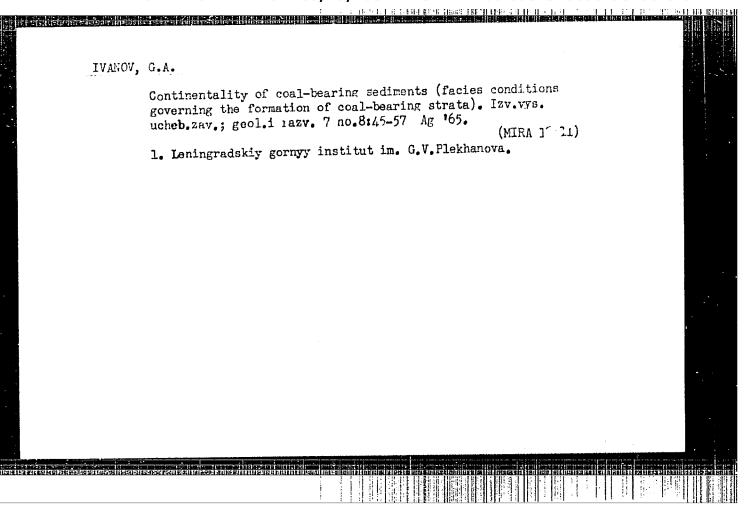
ASSOCIATION: Leningradskiy gosudarstvennyky pedagogicheskiy institut im. A. I. Gertsena (Leningrad State Pedagogical Institute)

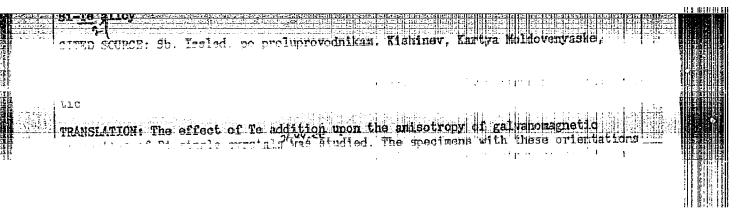
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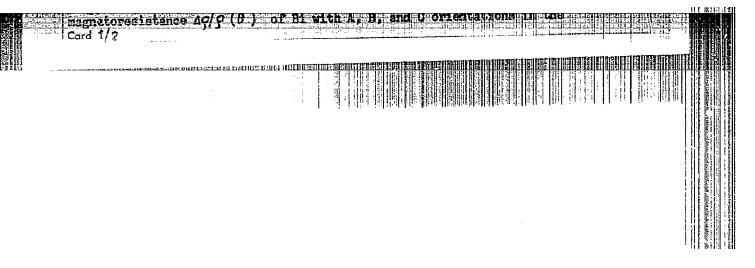
DATE ACQ: 31Mar64

ENCL: CL

Card 1/3







CIA-RDP86-00513R000619020019-3 "APPROVED FOR RELEASE: 08/10/2001

ACC NR: AR7000884

SOURCE CODE: UR/0058/66/000/009/E107/E107

AUTHOR: Ivanov, G. A.; Koposov, G. D.

TITLE: Electrical properties of pure bismuth and its alloys with tin over a wide range of temperatures

SOURCE: Ref. zh. Fizika, Abs. 9E852

REF SOURCE: Uch. zap. Leningr. gos. ped. in-ta im. A. I. Gertsena, v. 265,

TOPIC TAGS: bismuth, bismuth alloy, bismuth tin alloy, electric property, 1965, 205-213 bismuth base alloy, tin containing alloy, Hall coefficient, temperature variation, specific resistance

ABSTRACT: A study was made of the electrical properties of Bi and the Bi-Sn alloy within 77-273K. The amount of Sn was varied between 0.2 to 1.5 at. %. The Hall coefficient component $R_{1\,23}$ was positive in all the alloys. With a decrease in temperature the R₁₂₃ component was found to change its sign from negative to positive, reach a maximum, and begin to decrease. Whereas specific resistance Pu increases almost linearly with increasing temperature, Pas with increasing

Card 1/2

temperature reaches a maximum and behaves as a semiconductor. An increase in the amount of Sn brings about a monotonic increase in p₁₁. An analysis was made of the dependence of magnetic resistance on temperature and the amount of Sn. Tables are given of circular diagrams of the magnetic resistance of both pure and alloyed bismuth. Results obtained from single and multi-ellipsoid models of the valence band of Bi are discussed qualitatively. [Translation of abstract] [SP] SUB CODE: 20//

ACC NR: AR7000885 SOURCE CODE: UR/0058/66/000/009/E107/E107 AUTHOR: Ivanov, G. A.; Chistyakov, B. I. TITLE: Electrical properties of binary alloys of bismuth and tellurium and bismuth and tin over a wide range of temperatures SOURCE: Ref. zh. Fizika, Abs. 9E853 REF SOURCE: Uch. zap. Leningr. gos. ped. in-ta im. A. I. Gertsena, v. 265, 1965, 214-223 TOPIC TAGS: allow, bismuth alloy, binary alloy, binary bismuth alloy, biornuth tellurium alloy, bismuth tin alloy, electric property, high temperature affact, thermodertromation force ABSTRACT: A study was made of the effect of temperature within the -196 to 200C range on the Hall effect R, specific resistance , and the thermoelectromotive force coefficient α in polycrystalline samples of alloys of bismuth (Bi) and tin (Sn) and bismuth and tellurium (Te). In Bi-Te, R was found to increase with a decrease in temperature (T). When T is above room temperature, R(T) is at its maximum and shifts toward the region of higher temperatures with an increase in concentration of Te. In alloys with arbitrary amounts of Te, ρ (7) is

ACC NR: AR7000885

similar to that in pure Bi. At high temperatures, R in Bi—Sn differs little from R in pure Bi. When the temperature is decreased, R reaches a maximum, then changes its sign for the positive. The lower the Sn content, the lower the temperature at which the change of sign occurs. Curves $\alpha(T)$ are analogous to curves R(T). In the region of low temperatures, ρ increases with an increase in T and passes through the maximum, which is followed by a minimum and a subsequent tendency toward a value which corresponds to that of pure Bi. A qualitative evaluation is made of the results obtained. It is found that efficiency η in Te increases inversely with temperature. Yu. Ogrin. [Translation of abstract]

SUB CODE: 20//

Card 2/2

ACC NR: AR7000881

SOURCE CODE: UR/0058/66/000/009/E106/E106

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AUTHOR: Ivanov, G. A.

TITLE: Mobility of current carriers in bismuth alloys and the reluctance

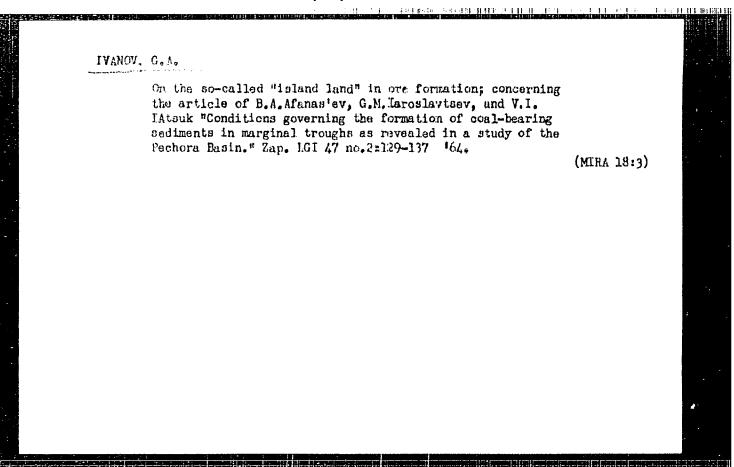
SOURCE: Ref. zh. Fizika, Abs. 9E844

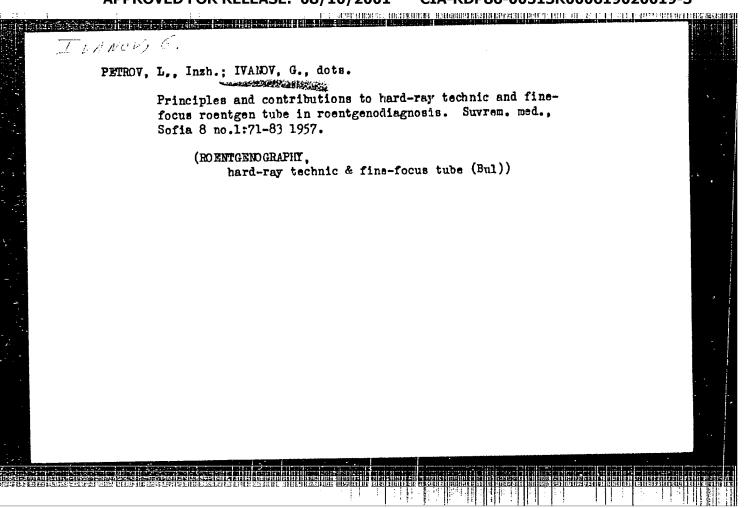
REF SOURCE: Uch. zap. Leningr. gos. ped. in-ta im. A. I. Gertsena, v. 265, 1965, 246-253

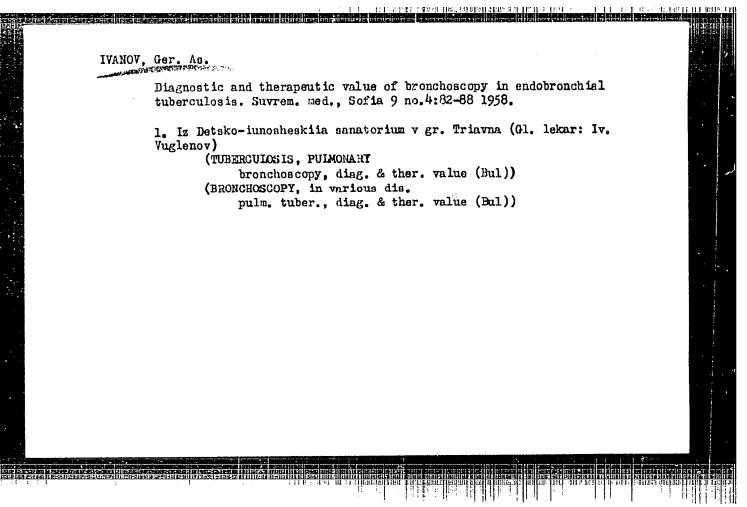
TOPIC TAGS: alloy, bismuth alloy, current carrier, magnetic reluctance hole mobility, reaction mobility, impurity band, any band at metical ABSTRACT: The mean mobilities of electrons and holes in Bi—Sn—Te alloys are calculated at room temperature. The calculation is based on the assumption that the band structure of Bi remains virtually unchanged with the addition of impurities. Changes are observed only in the position of the level of the chemical potential in the bands. A model is used, which takes into consideration the complex band structure in which the ellipsoids of equal energy in the K-space, are replaced by spheres. Comparisons with experimental results have shown that the mobilities are determined correctly and that the constant-energy surfaces remain relatively

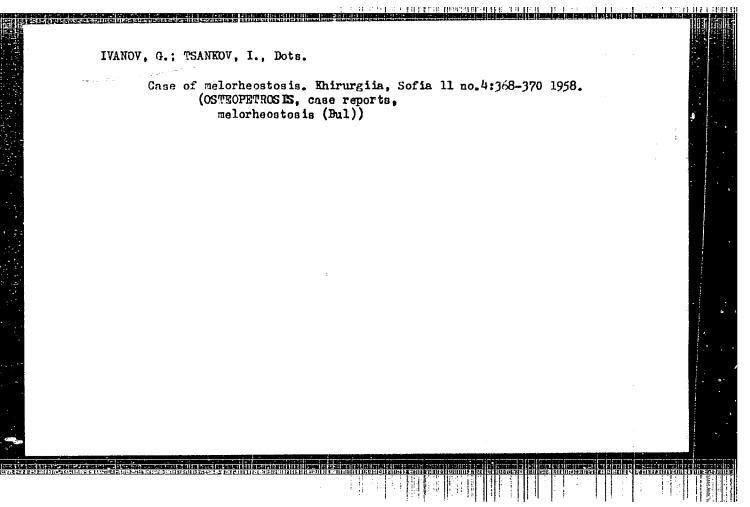
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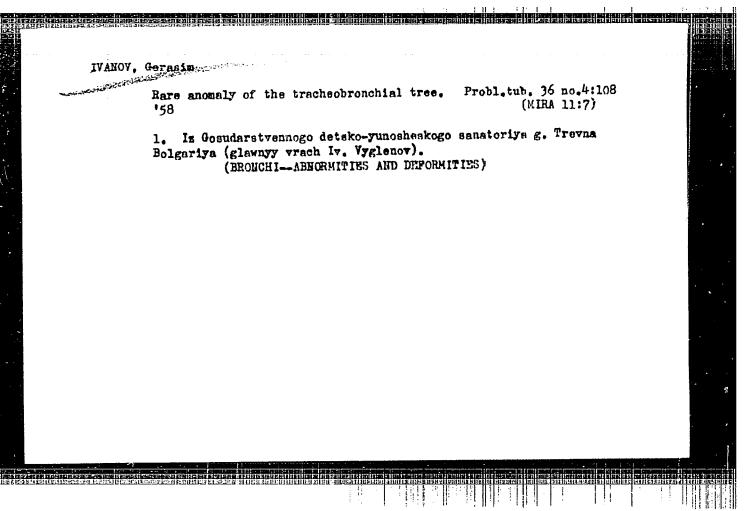
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out by the complexity of the configuration of the constant-energy. Ogrin. [Translation of abstract]	gy surfaces. [GC]
unchanged when the Fermi level rises, and that the reluctance in Bi as well as in the alloys is determined not by the thermal variance of velocities of the carriers,	

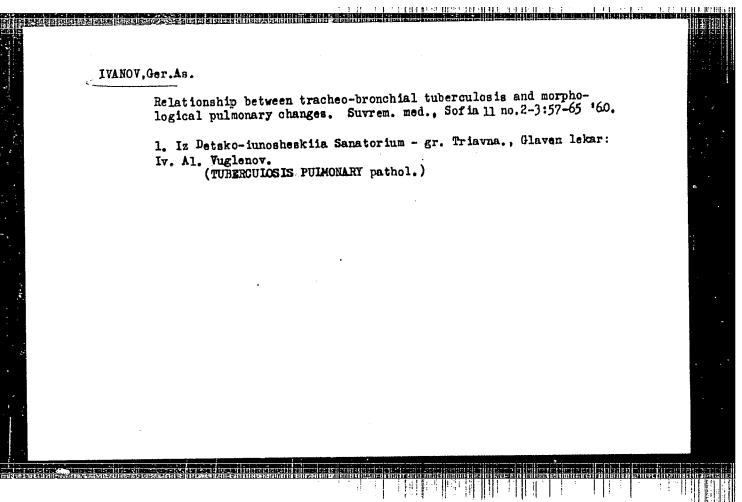


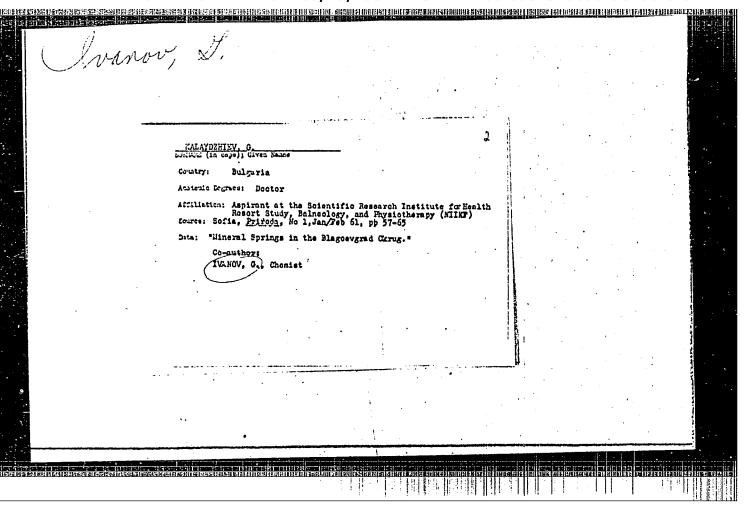












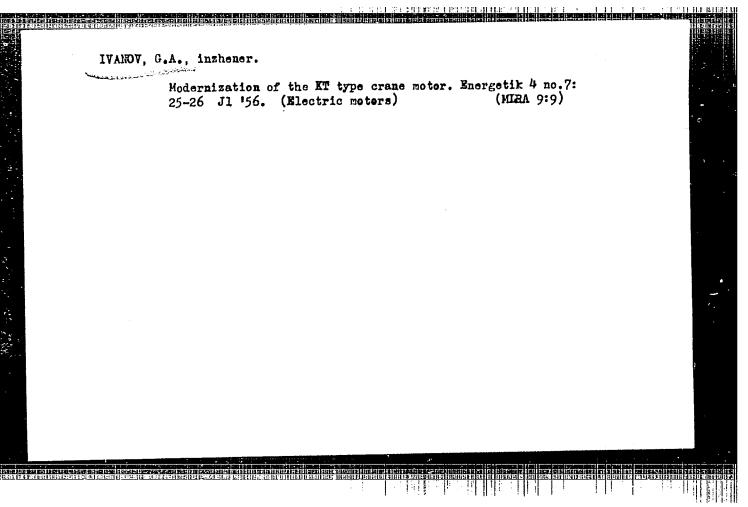
1 25921-66 JT ACC NR: AP5016680 SOURCE CODE: UR/01.09/65/01.0/006/2164/1166 AUTHOR: Ivanov, G. A.; Ryabova, L. A.; Savitskaya, Ya. S.; Eatskevich, T. L.; 53 Chelyshkov, S. P. ORG: none . TITIE: Second Scientific Session of the Scientific Council on Physical Electronics SOURCE: Radiotekhnika i elektronika, v. 10, no. 6, 1965, 1154-1156 TOPIC TAGS: physics conference, chemisorption, adsorption, semiconductor device, secondary electron emission, photoelectric property, thermoelectric property The second session of the conference on physical eledtronios was held 23-24 Nov 1964, with 142 delegates from 41 organizations in attendence to hear 18 reports in 3 sessions. The first session was dedicated to the question of chemisorbtion of various gasses on the surfactes of solids and questions of emission and antiemission coatings. The properties of chemical adsorbtion, as well as the influence of chemical adsorbtion on the operation of semiconductors and the structure of adsorbed films on crystals. Another reporter noted that the antiemission property of gold appears to take place only in the system goldbarium, not with barium oxide. The second session was dedicated Card 1/2

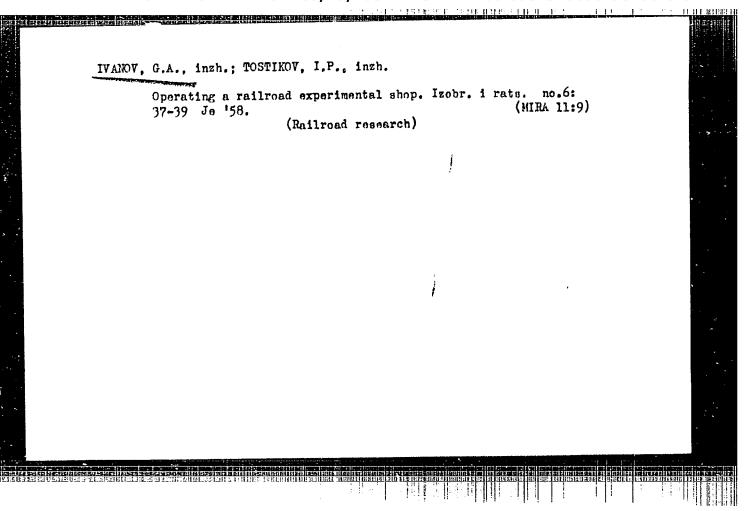
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	54
ORG: Institute of Applied Physics, AN MSSR, Kishinev (Institut priklad fiziki AN MSSR)	noy
TITLE: Some features of the influence of Sn and Te impurities on the anisotropy of the galvanomagnetic properties of bismuth	
SOURCE: Fizika tverdogo tela, v. 8, no. 4, 1966, 1293-1295	
TOPIC TAGS: tin, selenium, bismuth, galvanomagnetic effect, impurity level, magnetoresistance, Hall constant, bismuth base alloy, ternary alloy	
ABSTRACT: This is a continuation of earlier work by one of the authorization, FMM v. 16, 848, 1963 and earlier), where it was shown that, certain concentrations, ternary alloys of bismuth with Sn and Te have the same properties as pure bismuth, meaning that the Sn and Te cance each other out. The present study reports measurements of the angular dependence of the magnetoresistance and the Hall coefficient at room temperature, in a magnetic field of 18 kOe, for two such compensated cylindrical samples with different crystallographic orientations. The results showed that when the axis of the sample was parallel to the	at el ar —
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that of pure bismu	l the sample had galvand th. When the sample axi the magnetoresistance of	s was parallel to	the crystal-
ceeded that of a besample A, the diagethe additive, and with tin, and much Hall coefficient on tude than in pure	inary alloy with either ram remains symmetrical the magnetoresistance wa higher than that of the f the compensated sample bismuth. It is conclu	Sn or Te. In the regardless of the salower than that alloy with tellures was larger in abaded that although	case of nature of of the alloy lum. The solute mag- the influ-
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	IVANOV, G A .19	
	Novoye v tekhnike remonta parovozov; opyt parovozoremontnykh zavodov (Innovation in the technique of repairing locomotives, by) G. A. Ivanov, I. M. Shatsman. Moskva, Transzheldorizdat, 1955.	
	96 p. illus., diagrs.	. "
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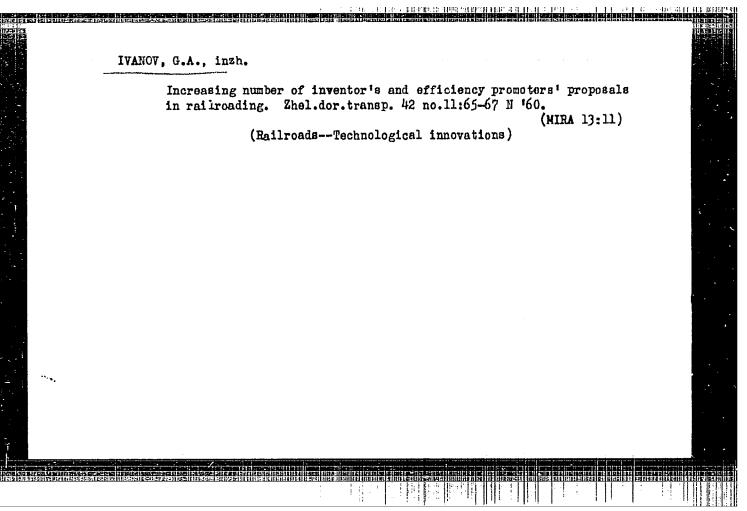
IVANOV, Georgiy Andreyevich; SOROKIN, N.N., red.; VERINA, G.P., tekhn.red.

[Mechanization of clinker removal operations at stations]

Mikhanizirovannaia uborka shleka na stantsiiakh. Moskva,

Gos.transp.zhel-dor.izd-vo, 1959. 61 p. (MIRA 13:1)

(Railroads--Equipment and supplies) (Ash disposal)



SHCHUKIN, Mikhail Mikhaylovich; ZAKIN, Ya.Kh., kand.tekhn.nsuk, retsenzent;

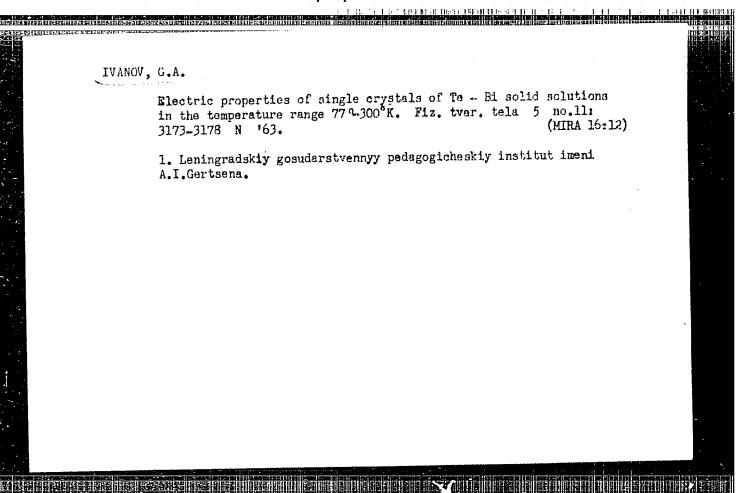
YANOY, G.A., kand.tekhn.nsuk, red.; SIMOHOYSKIY, N.Z., red.;

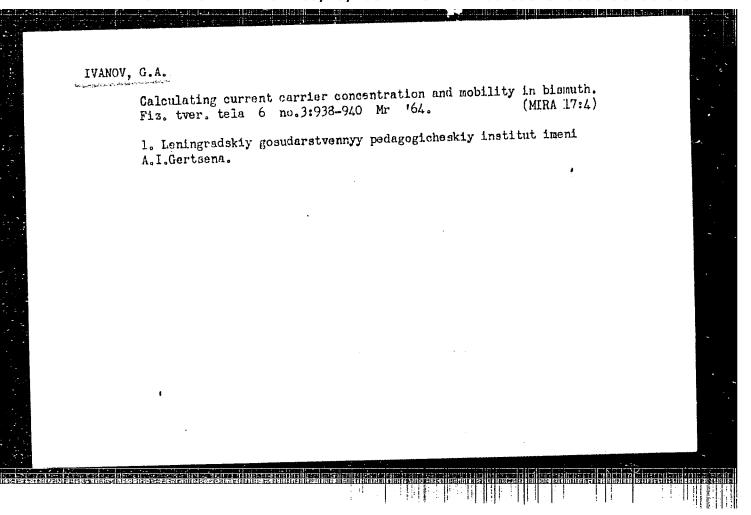
SPERANSKYA, O.V., tekhn.red.

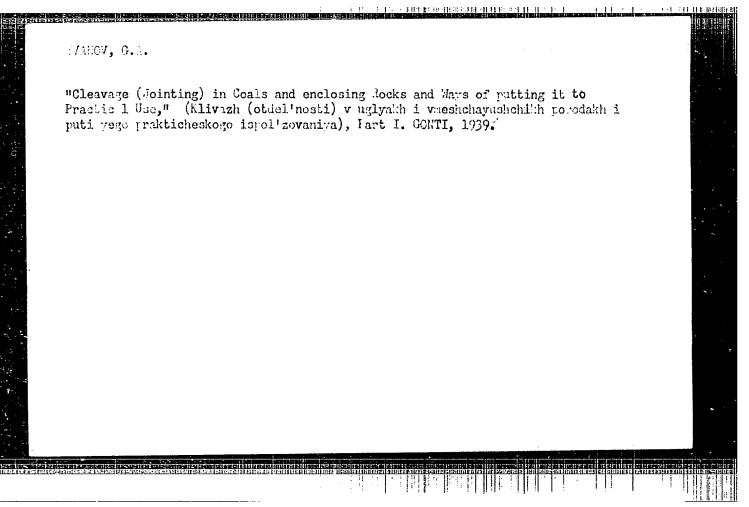
[Coupling systems for sutomobiles and tractors; design, theory, ond calculation] Steepnys ustroistva sytomobilei i tiegachei; konstruktaila, teoriia i reschet. Moskva, Gos.nauchno-tekhn. izd-vo manhinostroit.lit-ry, 1961. 206 p.

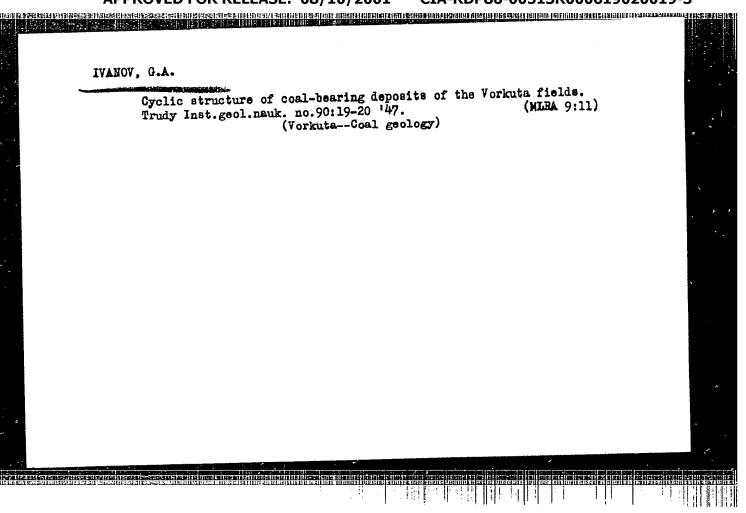
(MIRA 14:4)

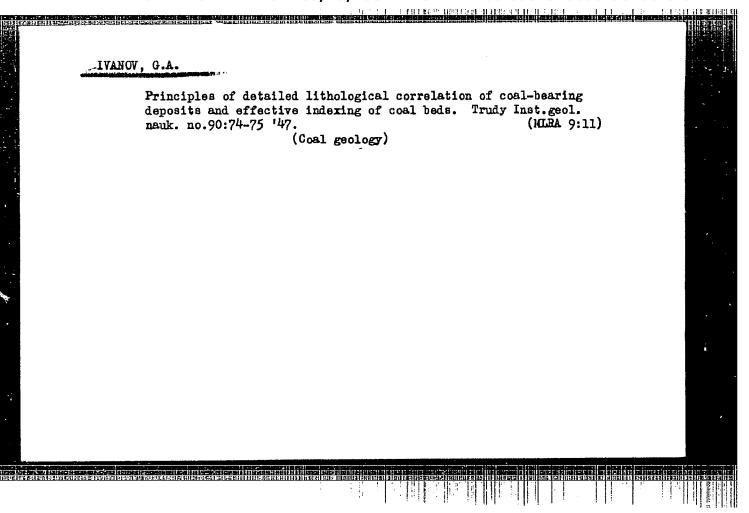
(Couplings) (Automobile trains)

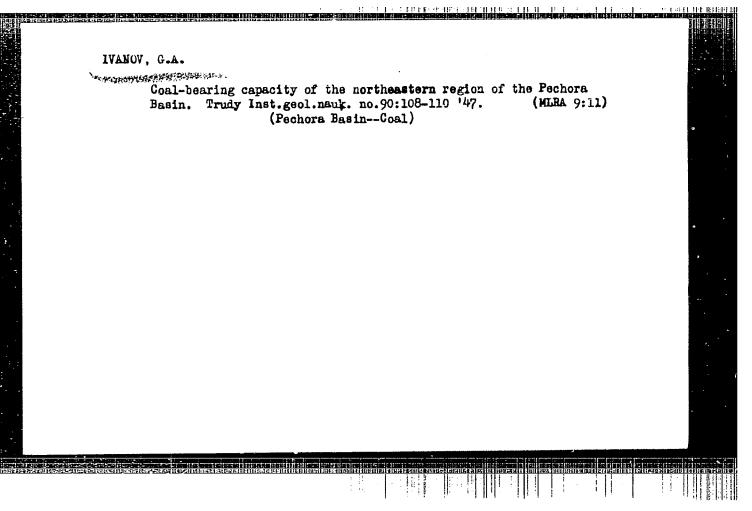


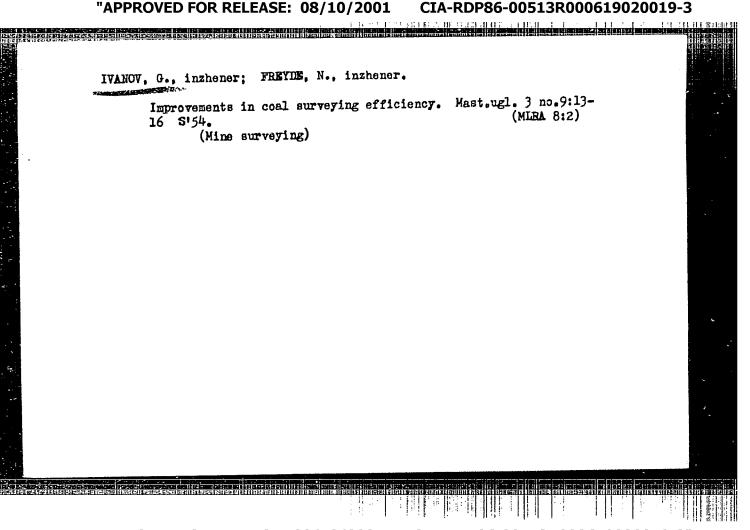








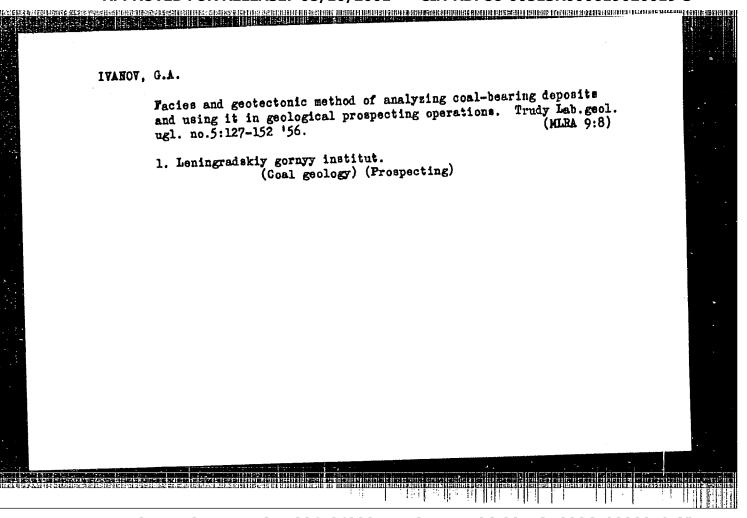




IVANOV, G.

Freide, N. Improvement of rationalizers in surveying coal deposits. p. 86. MINNO DELO, Sofiya, Vol. 10, no. 1, Jan./Feb. 1955.

SO: Monthly List of East European Accessions, (EEAL), LC, Vol. 4, no. 10, Oct. 1955, Uncl.



IVANOV, Grigoriy Aleksandrovich Name:

Regularity of structure, formation, and change of coal-bearing deposits Dissertation:

TALL TO SAFERE A SAFE DEFINED FROM THE CONTROL OF A CHARGE OF THE ORIGINAL PROPERTY OF THE ORIGI

(formations)

Degree: Doc Geol-Min Sci

Affiliation: /not indicated/

Defense Date, Place: 12 Jun 57, Council of Leningrad Order of Lenin and Order of Labor Red Banner

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Mining Inst imeni Plekhanov

10 Nov 57 Certification Date:

Source: BMVO 24/57

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VANOV, G. A. ABRAMOV, S.K., kand.tekhn.nauk; AVERSHIN, S.G., prof., doktor tekhn.nauk; AMMOSOV, I.I., doktor geol.-min.nauk; ANDRIYEVSKIY, V.D., inzh.; AMTROPOV, A.N., inzh.; AFANAS'YEV, B.L., inzh.; BERGHAN, Ya.V., inzh.; BLOKHA, Ye.Ye., inzh.; BOGACHEVA, Ye.N., inzh.; BUKRINSKIY, V.A., kand.tekhn.nauk; VASIL'YEV, P.V., doktor geol.-min.nauk; VINOGRADOV, B.G., inzh.; GOLUBEV, S.A., inzh.; GORDIYENKO, P.D., inzh.; GUSEV, N.A., kand.tekhn.nauk; DOROKHIH, I.V., kand.geol.-min.nauk; KAIMYKOV, G.S., inzh .; KASATOCHKIN, V.I., doktor khim nauk; KOROLEV, I.V., inzh .; KOSTLIVTSEV, A.A., inzh.; KRATKOVSKIY, L.F., inzh.; KRASHENINNIKOV, G.F., prof. doktor geol.-min.nauk; KRIKUNOV, L.A., inzh.; LEVIT, D.Ye., inzh.; LISITSA, I.G., kand.tekhn.nauk; LUSHNIKOV, V.A., inzh.; MATVEYEV, A.K., dots., kand.geol.-min.nauk; MEFURISHVILI, G.Ye., iznh.; MIRONOV, K.V., inzh.; MOLCHANOV, I.I., iznh.; NAUMOVA, S.N., starshiy nauchnyy sotrudnik; MEKIPELOV, V.Ye., inzh., PAVIOV, F.F., doktor tekhn.nauk; PANYUKOV, P.N., doktor geol.-min.nauk; POPOV, V.S., inzh.; PYATLIN, M.P., kand.tekhn. nauk; RASHKOVSKIY, Ya.R., inzh.; ROMANOV, V.A., prof., doktor tekhn. nauk; RYZHOV, P.A., prof., doktor tekhn.nauk; SELYATITSKIY, G.A., inzh.; SPERANSKIY, M.A., inzh.; TERENT'YEV, Ye.V., inzh.; TITOV, N.G., doktor khim.nauk; GOKAREV, I.F., inzh.; TROYANSKIY, S.V., prof., doktor geol .min.nauk; FEDOROV, B.D., dots., kand.tekhn.nauk; FEDOROV, V.S., inch. [deceased]; KHOMENTOVSKIY, A.S., prof., doktor geol.-min.nauk; TROYANOV-SKIY, S.V., otvetstvennyy red.; TERPIGOREV, A.M., red.; KRIKUNOV, L.A., red.; KUZNETSOV, I.A., red.; MIRONOV, K.V., red.; AVERSHIN, S.G., red.; BURTSEV, M.P., red.; VASIL'YEV, P.V., red.; MOLCHANOV, I.I., red.; RYZHOV, P.A., red.; BALANDIN, V.V., insh., red.; BLOKH, I.M., kand. tekhn.nauk, red.; BUKRINSKIY, V.A., kand.tekhn.nauk, red.; VOLKOV, K.Yu., inzh., red.; VOROB'YEV, A.A., inzh., red.; ZVONAREV, K.A., prof. doktor (Continued on next card) tekhn nauk, red.

ARRAMOV, S.K.--- (continued) Card 2.

ZDANOVICH, V.G., prof.,doktor tekhn.nauk, red.; LYAHOV. G.A.; doktor geol.-min.nauk, red.; KARAYAYEV, N.M., red.; KOROTKOV, G.V., kand.geol.-min.nauk, red.; COROTKOV, M.V., kand.tekhn.nauk, red.; MAKKAYETEV, A.A., doktor geol.-min.nauk, red.; OMEL'CHENKO, A.M., kand.tekhn.nauk, red.; SENDERZON, E.M., kand.geol.-min.nauk, red.; Ushakov, I.N., dots., kand. tekhn.nauk, red.; KAROLEYA, T.I., red.izd-va; KACHALKIMA, Z.I., red.izd-va; FROZOROVSKAYA, F.L., tekhn.red.; NADEHINSKAYA, A.A., tekhn.red.

[Mining; an encyclopedia handbook] Gornoe delo; entsiklopedicheskii apravochnik. Glav. red. A.M.Terpigorev. Moskva, Gos.pauchno-tekhn. izd-vo lit-ry po ugol'noi promyshl. Vol.2. [Geology of coal deposits and surveying] Geologiis ugol'nykh mestorozhdenii i marksheiderskoe delo. Redkolegiis toma S.V.Troianskiy, 1957. 646 p. (MIRA 11:5)

1. Chlen-korrespondent AN SSSR (for Karaveyev)

(Coal geology-Dictionaries)

"APPROVED FOR RELEASE: 08/10/2001 CIA-RDP86-00513R000619020019-3 ASSESSMENT OF THE PROPERTY OF

EVANOV, G.A.

AUTHOR:

Zhemchuzhnikov, Yu.A.

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11-1-1/29

TITLE:

Similarities and Differences of Features Between Pacies, Facies-Cyclic and Facies-Geotectonic Methods of Studying Coal-Bearing Strata (Skhodstvo i razlichiya mezhdu fatsial'nym, fatsial'no-tsiklicheskim i fatsial'no-geotektonicheskim metodami izucheniya uglenosnykh tolshch)

PERIODICAL:

Izvestiya Akademii Nauk SSSR, Seriya Geologicheskaya, 1958, # 1, pp 3-11 (USSR)

ABSTRACT:

At the second Coal Geological Conference held in March 1955, the lectures of G.A. Ivanov, T.A. Ishina, V.V. Koperina, N.V. Rengarten and others dealt with different methods of examining coal-bearing strata. G.A. Ivanov and the author belong to a group of geologists who regard periodicity as one of the most important features of coal-bearing strata. The author elaborates on the similarities and differences existing between his views and those of G.A. Ivanov. Ivanov proposes to conduct the observations first of the facies, and afterwards of geotectonics, and therefore his method is called the facial-geotectonic method. However, his method starts with the differentiation according to granulometric differences, whereby coal and limestone are regarded as the

Card 1/4

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Similarities and Differences of Features Between Facies, Facies-Cyclic and Facies-Geotectonic Methods of Studying Coal Bearing Strata

rocks with the finest granules. G.A. Ivanov emphasizes that his proposed facial-geotectonic method based on granulometric examinations and on the development of marked facies can chiefly be used by geologists prospecting for coal. G.A. Ivanov sees the essential difference between his method and the facial-cyclical analysis in the fact, that his method does not require the difficult separation and determination of numerous types of lithological rocks and their facial classification. He proposes to determine facies by cycles, and not cycles by facies, believing this method to be less difficult and more accurate. The author draws attention to the fact that not separate facies are determined by the Ivanov method, but groups of facies which are in contact with marked facies. The facial-cyclical method was successfully applied in the Kuznetsk and many other coal basins. Summarizing it may be stated that the facial geotectonic analysis of G.A. Ivanov has many similarities with the facial-cyclical method, in contrast to the facial analysis which disregards the rules of periodicity. In the lectures of T.A. Ishina, V.V. Koperina and others it is stated that facial

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11-1-1/29

Similarities and Differences of Features Between Facies, Facies-Cyclic and Facies-Geotectonic Methods of Studying Coal Bearing Strata

analysis represents the study of primary or genetic properties of rocks originating during the process of sedimentation and subsequent diagenetic transformation. Based on the total of these indications, conclusions are drawn pertaining to the conditions under which sedimentation took place and the facial composition of the coal-bearing strata is established. The author disagrees with this view, in as much as it does not consider the importance of sequence or alternation of rocks for the formation of facies, their paragenetic composition. Summarizing it may be stated that lithologists, using facial analysis of the improved stage, i.e. as a facialcyclical method, will obtain better results and will further improve the method itself. Lithology of coal-bearing strata requires further studies and exchanges of experiences on the matter. At the present time there are no differences existing between the methods of approach which cannot be overcome as long as they are not throttled by denying the geotectonic factor of alternation of rocks or by disregarding the importance of studying the individual lithologic characteristics of rocks or by ignoring the importance of establishing the

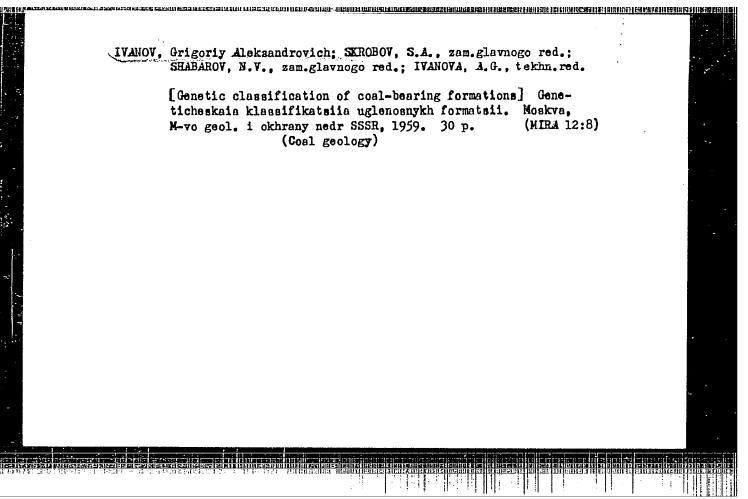
Card 3/4

Similarities and Differences of Features Between Yacies, Factes-Cyclis and Factes-Geotectomic Methods of Studying Coal Bearing Strata different facies by all available methods.

There are 18 Russian references.

AVAILABLE: Library of Congress

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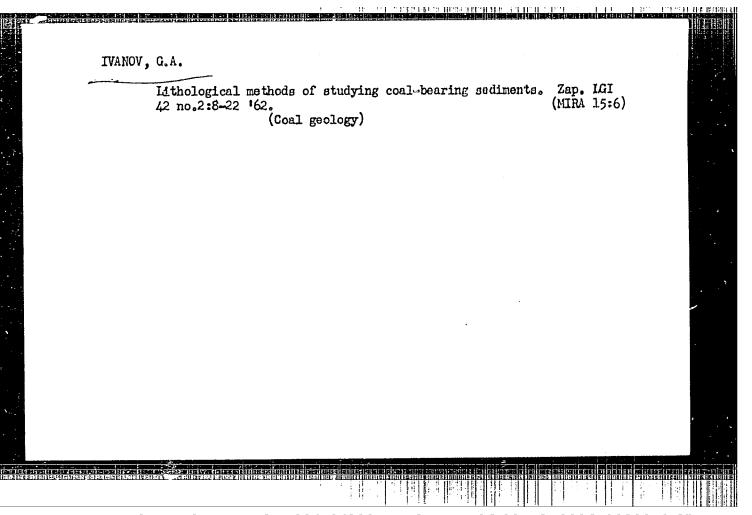


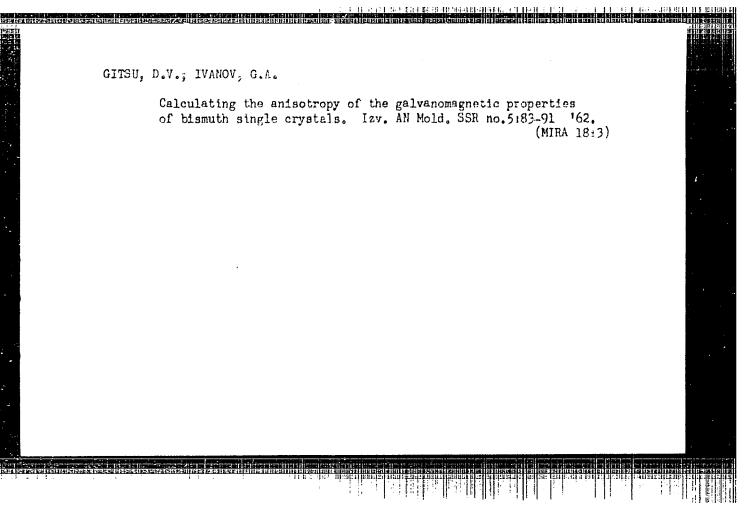
MATVEYEV, Aleksandr Kirillovich; VASIL'YEV, P.V., doktor geol.-mineral. nauk, retsenzent; KRAVTSOV, A.I., doktor deol.-mineral.nauk, retsenzent; IVANOV, G.A., doktor geol.-mineral.nauk, retsenzent; MIRONOV, K.V., nauchnyy red.; KOROLEVA, T.I., red.izd-va; KONDRAT'YEVA, M.A., tekhn.red.

[Geology of coel basins and deposits in the U.S.S.R.] Geologia ugol'nykh basseinov i mestorozhdenii SSSR. Moskva, Gos.nauchnotekhn.izd-vo lit-ry po gornomu delu, 1960. 495 p.

(MIRA 13:11)

(Coal geology)





SKROBOV, S.A., glav. red.; TYZHNOV, A.V., zam. glav. red.; SHABAROV, N.V., zam. glav. red.; AMMOSOV, I.I., redaktor; red.; BURTSEV, D.N., red.; IVANOV, G.A., red.; KOROTKOV, G.V., red.; KOTLUKOV, V.A., red.; KUZNETSOV, I.A., red.; MIRONOV, K.V., redaktor; MOLCHANOV, I.I., redaktor; MEKIPELOV, V.Ye., red.; PONOMAREV, T.N., red.; POPOV, V.S., red.; PROKHOROV, S.P., red.; YAVORSKIY, V.I., red.; LAGUTINA, V.V., red. toma; LEVENSHTEYN, M.L., red. toma; SHIROKOV, A.Z., red. toma; IZRAILEVA, G.A., red.izd-va; KROTOVA, I.Ye., red. izd-va; IVANOVA, A.G., tekhn. red.

[Geology of coal and combustible shale in the U.S.S.R.]Geologiia mestorozhdenii uglia i goriuchikh slantsev SSSR. Glav. red. I.I. Ammosov i dr. Moskva, Gosgeoltekhizdat. Vol.1.[Coal basins and deposits in the south of the European part of the U.S.S.S;;Donets Basin, Dnieper Basin, Lvov-Volyn' Basin, deposits of the western provinces of Moldavia and the Ukraine, White Russia, Transcaucasia and the Northern Caucasus] Ugol'nye basseiny i mestorozhdeniia iuga Evropeiskoi chasti SSSR; Donetskii bassein, Dneprovskii bassein, L'vovsko-Volynskii bassein, mestorozhdeniia zapadnykh oblastei Ukrainy i Moldavii, Belorussii, Savernogo Kavkaze i Zakavkaz'ia. 1963. 1210 p. (MIRA 17:3)

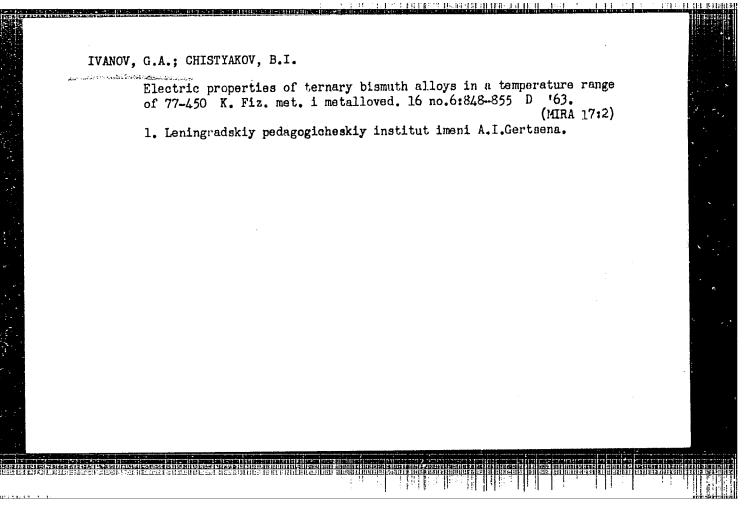
1. Russia (1923- U.S.S.R.) Gosudarstvennyy geologicheskiy komitet.

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IVANOV, G.A.; POPOV, A.M.

Electric properties of bismuth-antimony alloys. Fiz. tver tela 5 no.9:2409-2419 S '63. (MIRA 16:10)

1. Leningradskiy gosudarstvennyy pedagogicheskiy institut im. A.I.Gertsena.



BETEKHTIN, A.G. (deceased); GOLIKOV, A.S.; DYBKOV, V.F.; LYAKOV, G.A.; KARYAKIN, A.Y.; KIRYUKOV, V.V.; KUFROV, I.G.; MAGAKIYAN, I.G.; STROMA, P.A.; TATARNOV, P.M.; CHEKHOVICH, Ye.D.; SMIRNOV, V.I., retsenzent

[Course in mineral deposits] Kurs mestorozhdenii poleznykh iskopaemykh. Izd.3., perer. i dov. Monkva, Medra, 1904.

529 p.

IVANOV, G.A., doktor geol.-miner. nauk, otv. red.

[History of the coal accumulation in the Pechera Basin] Istoriia uglenakopleniia v Pecherskom basseine. Mo-skva, Nauka, 1965. 246 p. (MIRA 18:9)

1. Leningrad. Vsesoyuznyy nauchno-issledovatel'skiy geologicheskiy institut. Otdel geologii uglya i gc-ryuchikh slantsev.

	L 04229-67 EWT(1)/EWT(m)/EWF(w)/T/EWP(t)/ETI IJF(c) JD/GC ACC NR: AR6031897 SOURCE CODE: UR/0058/66/000/006/E131/E131 AUTHOR: Ivanov, G. A.	
! _	TITLE: Correlation between electrical and galvanomagnetic properties of single- crystal and polycrystal specimens	
	SOURCE: Ref. zh. Fizika, Abs. 6E1021	
	REF SOURCE: Uch. zap. Leningr. gos. ped. in-ta im. A. I. Gertsena, v. 265, 1965, 193-204	
	TOPIC TAGS: crystal property, single crystal property, polycrystal property, galvanometric property	-
	ABSTRACT: It is shown at what anisotropy values and experimental errors it is possible to use simple formulas which link the electrical properties of single-crystals and polycrystals. The conclusions are confirmed by experimental data for Bi and its alloys. [Translation of abstract]	
ź.	SUB CODE: 09, 20/	
	(1/1 sla)	

ACC NR: AP6026703 SOURCE CODE: UR/0181/66/008/008/2460/2:61

AUTHOR: Grabov, V. M.; Ivanov, G. A.

ORG: Leningrad State Pedagogical Institute im. A. I. Gertsen (Leningradskiy gosudarstvennyy pedagogicheskiy institut)

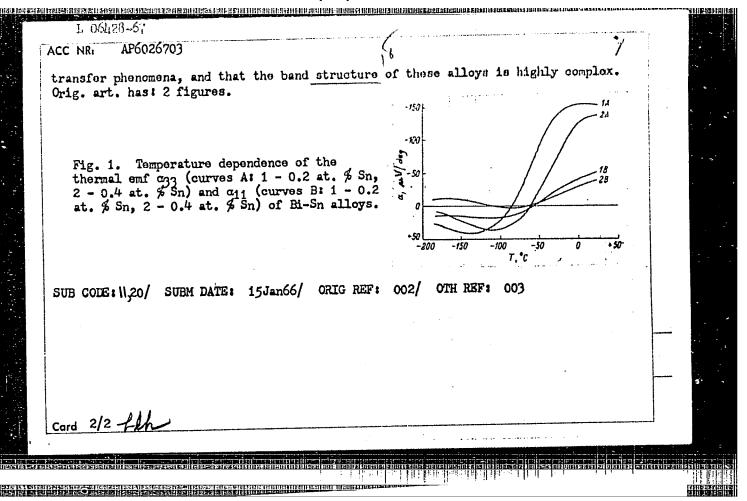
TITIE: Behavior of differential thermal emf in bismuth alloys

SOURCE: Fizika tverdogo tela, v. 8, no. 8, 1966, 2460-2461

TOPIC TAGS: bismuth alloy, tin alloy, thormal emf

ABSTRACT: The temperature dependence of the differential thermal enf α_{11} and α_{33} of Bi-Sn alloys containing various amounts of tin was studied (Fig. 1). As the temperature drops, the sign of the differential thermal emf of the alloy with 0.2 at. % Sn changes from negative to positive, but the anisotropy of the thermal emf romains considerable. This indicates current carriers belonging to several nonequivalent groups participate in the transfer phenomena. In all of the Bi-Sn alloys containing up to 1.0 at. % Sn, the nature of the temperature dependence of α_{33} remains the same. As the Sn content increases, the point at which the sign of α_{33} changes shifts toward higher temperatures. In the alloy with 0.4 at. % Sn, the thermal emf α_{11} becomes negative at low temperatures. In alloys with a high Sn content, α_{11} is negative in the entire 80-300 % range. This fact and the strong anisotropy of the thermal emf in all the Bi-Sn alloys indicate that not only holes, but also electrons participate in the

Card 1/2



ACC NR: AR6033792 SOURCE CODE: UR/0058/66/000/007/E103/E103

AUTHOR: Glukhova, T. I.; Grabov, V. M.; Ivanov, G. A.; Popov, A. M.

TITLE: Electrical properties of quasi-binary alloys (Bi-Sb)-Te

SOURCE: Ref. zh. Fizika, Abs. 7E773

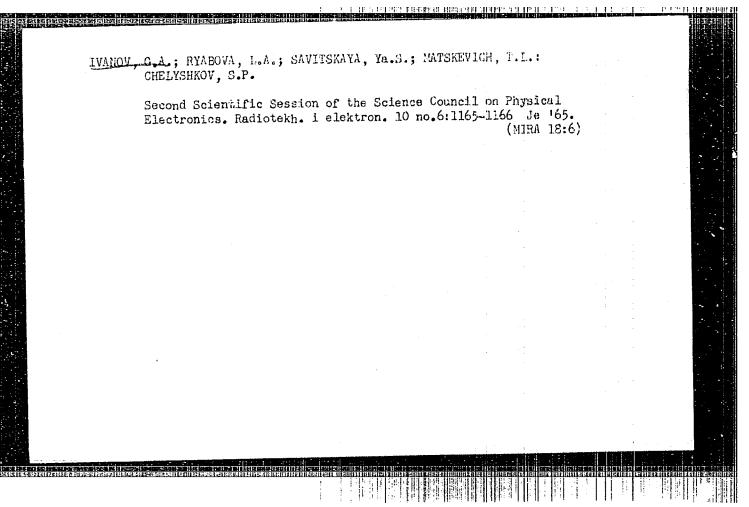
REF SOURCE: Uch. zap. Leningr. gos. ped. in-ta im. A. I. Gertsena, v. 265, 1965, 234-241

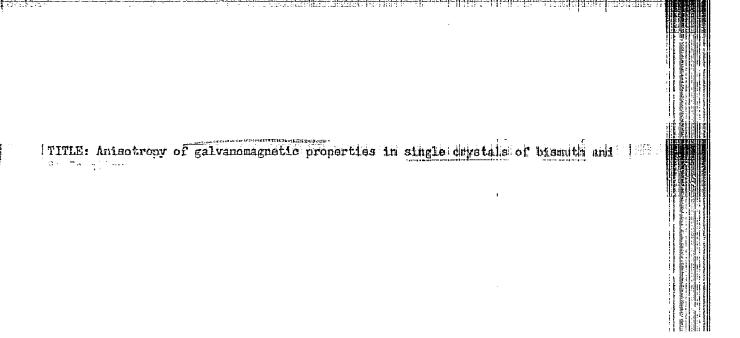
TOPIC TAGS: Hall effect, thermoelectromotive force, bismuth alloy, antimony alloy, tellurium alloy, temperature dependence, quasibinary alloy, binary alloy, conduction band

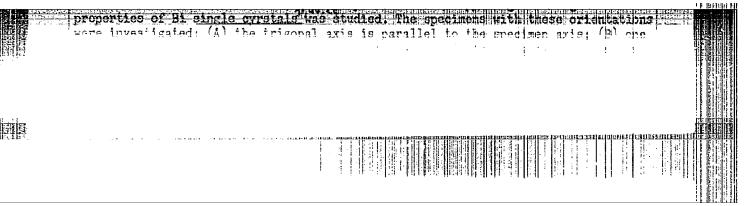
ABSTRACT: On the basis of investigation of the Hall effect, the specific resistance (ρ) and the thermoelectromotive force, a study is made of the structure of the conduction band in single and polycrystalline alloys (Bi-Sb)-Te, containing conduction band in single and polycrystalline alloys (Bi-Sb)-Te, containing 3, 6, 8, 10, 15, and 20 at % of Sb, and 0.1, 0.2, and 0.3 at % of Te. It is found that the addition of T lowers ρ , while the addition of Sb raises it in comparison with the ρ of initial Bi-Sb alloys. The values of effective electron masses found (m*) correspond to the values m* in the initial alloys. Depending on the concentra-

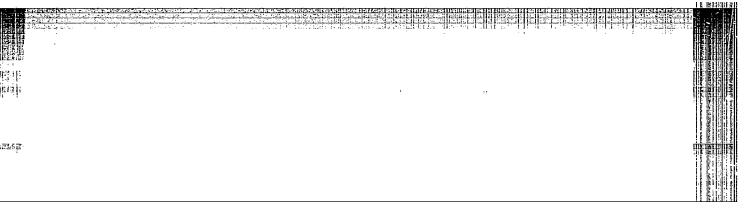
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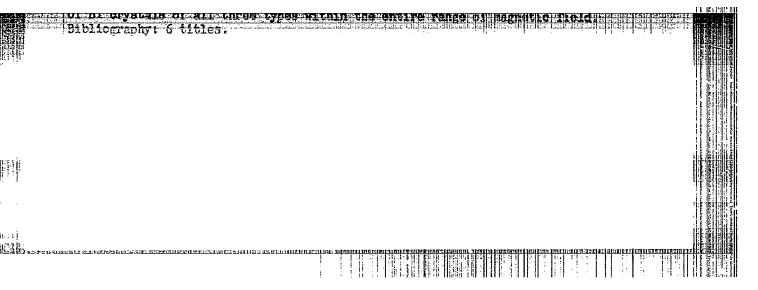
Smith [RZhFiz.	, 1963, 7E6	17], obtained at 1.3	nges is in accord with the dat K, which indicates a low ten l. [Translation of abstract]	ipera- [GC]
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DEMENTITY, v.M.; MERRICHATEV, Yu.P.; TISHOMENRO, A.T.; KHVASUKHIN, Yu.I.;
IYANOV, G.A.

Flameless burning of gas in a furnace with a fluidized bod. Gaz.
prom. 10 no.6:29-32 '65.

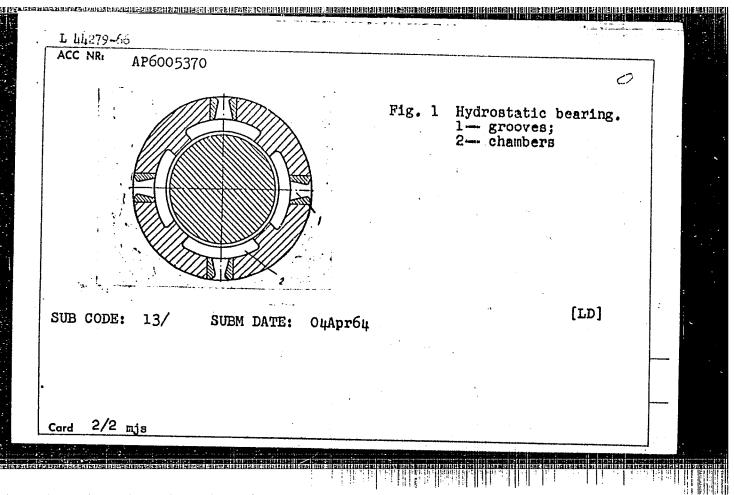
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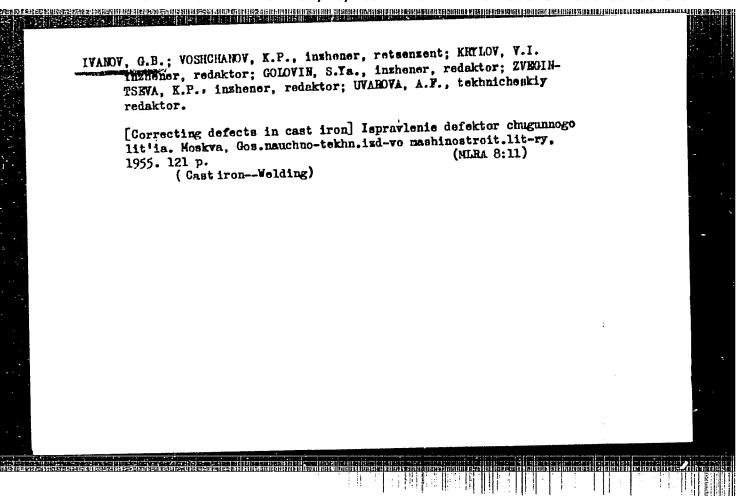
ZHDANOV, M.M.; KOSTRYUKOV, G.V.; ASFANDIYAROV, Kh.A.; MAKSUTOV, R.A.;
KONDAKOV, A.N.; TURUSOV, V.M.; SILIN, V.A.; PILYUTSKIY, O.V.;
SHELDYBAYEV, B.F.; PETROV, A.A.; SMIRNOV, Yu.S.; KOLESNIKOV,
A.Ye.; DROZDOV, I.P.; IVANTSOV, O.M.; TSYGANOV, B.Y.;
KORNONGCOV, A.P.; VDOVIN, K.I.; ALEKSEYEV, L.A.; GAYDUKOV, D.T.;
LIPTWESSKIY, A.Ya.; DANYUSHEVSKIY, V.S.; VPEDISHCHEV, I.A.;
ALEKSEYEV, L.G.; KRASYUK, A.D.; IVANOV, G.A.

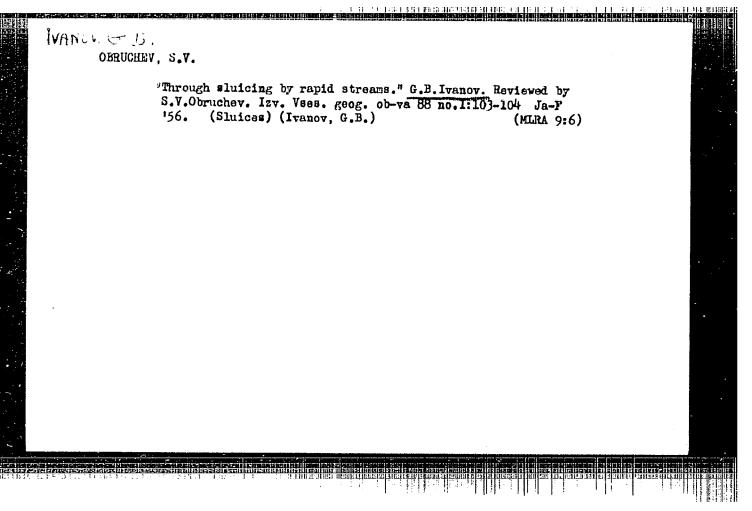
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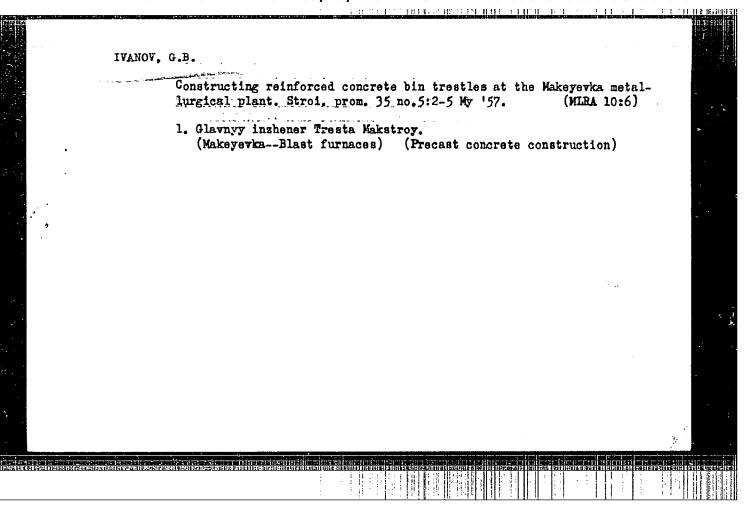
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no. 1, 1966, 117 TOPIC TAGS: bearing, labstract: This Author with grooves and a conto the friction surfac	hydrostatic bearing Learny & Certificate introduces a hydrost trol mechanism for feeding the lues. For greater reliability and mechanism is two grooves tapering ke groove is more tapered than thert. has: I figure.	atic bearing // bricating fluid ease of con- toward each
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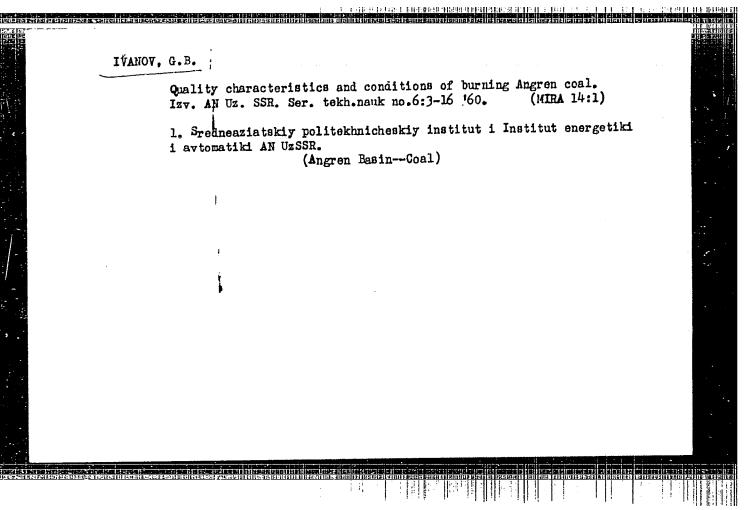
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AUTHORS: Ivanov, G.D., Bortnikov, M.G. and Zatulovskiy, N.M.

STEETE STEETE

TITIE: Modifications to the Control Circuits for Lifting Tables on a Plate Mill to Shorten the Rolling Cycle (Izmeneniye skhemy upravleniya pod yemnykh stolov tolstolistovogo stana dlya sokrashcheniya tsikla prokatki)

PERIODICAL: Promyshlennaya Energetika, 1958, Vol.13, No.3, pp. 18 - 19 (USSR).

ABSTRACT: This is a suggestion that meceived fifth premium in an All-Union competition for the economy of electric power.

An important factor in determining the time required to roll a billet on a plate mill is the time required to raise and lower the tables. Lowering seldom causes delay, because the operator can commence to lower them before the work leaves the rolls. However, if the raising is commenced too soon, damage may be done.

At the works imeni Petrovskiy, the electric motors driving the table lifts were controlled by the circuit given in Fig.1. An oscillogram taken when the motor was working with this control circuit is given in Fig.2, and shows that the motor is accelerating thoughout the period of lifting of the table. It was, therefore, desirable to increase the acceleration of the motor. After trying different values of starting resistance and delay

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Modifications to the Control Circuits for Lifting Tables on a Plate Mill to Shorten the Rolling Cycle

time of the accelerating relay, the new circuit shown in Fig.3 was proposed. It contains no accelerating relay nor counter-current relay, and a few other parts are left out. An oscillogram of the operation of the motor with the new circuit is given in Fig.4. The acceleration time has been cut from 2.5 to 0.9 sec and the total time required for lifting is cut from 4.38 to 3.25 sec. The total time saved in relling a sheet is 4 sec; thus, it was possible to roll a further 4 000 tons a year of sheet, whilst saving some 200 000 kWh of electric power. There are 4 figures.

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GRIGOR'YEV, B.V.; KIPERMAN, S.Ya.; IVANOV, G.F.; RYABINOK, A.G., red.; TELYASHOV, R.Kh., red.izd-va; GVIRTS, V.L., tekim.red.

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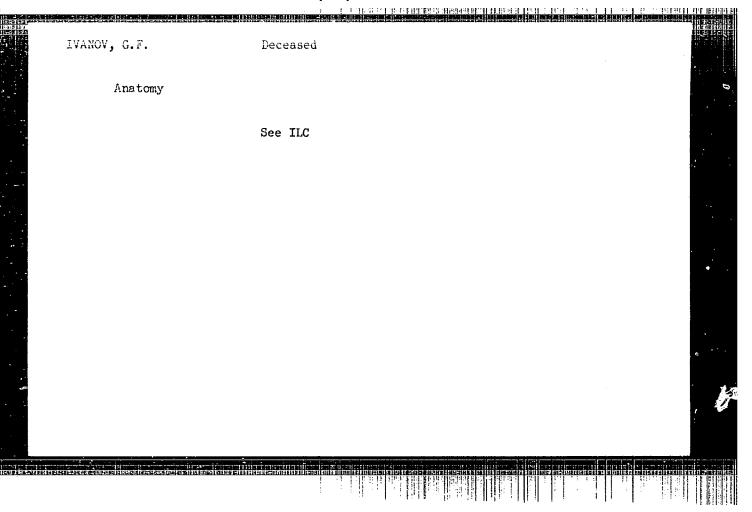
[New method of anode mechanical working of metals with a band] Novyi sposob obrabotki metallow metodom anodnogo to-cheniia lentoi. Leningrad, 1963. 15 p. (Leningradskii dom nauchno-tekhnicheskoi propagandy. Obmen peredovym opytom. Seriia: Elektrotekhnologicheskie protsessy i ustroistva, no.8)

IVANOV, G. F.

"Study of the Conditions for Obtaining Spongy Iron for the Complex Hydroflotation Process of 'Aeroflotation'." Sub 19 Nov 51, Moscow Inst of Nonferrous Metals and Gold imeni M. I. Kalinin Land Secondary Sec

Dissertations presented for science and engineering degrees in Moscow during 1951.

SO: Sum. No. 480, 9 May 55



ZEFIROV, A.P., professor, doktor tekhn. nauk, red.; IVANOV, G.F., kand. tekhn. nauk, red.; NEVSKIY, B.V., kand. tekhn. nauk, red.; SAGURO, M.A., red.; MAZEL', Ye.I., tekhn. red.

[Transactions. Selected reports by foreign scientists] Trudy. [Izbran-nye doklady inostrannykh uchenykh] Moskva, Izd-vo Glav. uprav. po ispol'zovaniiu atomnoi energ. pri Sovete Ministrov SSR. Vol.7. [Technology of atomic raw products] Tekhnologiia atomnogo syr'ia. Pod obshchei red. A.P.Zefirova. 1959. 656 p. (MIRA 14:7)

1. Vtoraya mezhdunarodnaya konferentsiya po mirnomu ispol'zovaniyu atomnoy energii, Zheneva, 1958.

(Uranium) (Thorium)